

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

PLICANT:

McGill et al.

GROUP:

2811

SERIAL NO:

10/632,442

EXAMINER: Unknown

FILED:

08/01/2003

FOR:

Sir:

YELLOW-GREEN EPITAXIAL TRANSPARENT SUBSTRATE-LEDS

AND LASERS ON A STRAINED-INGAP QUANTUM WELL GROWN

ON AN INDIRECT BANDGAP SUBSTRATE

Mail Stop DD **Commissioner of Patents** P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

In compliance with 37 C.F.R. §§1.56, 1.97, and 1.98, Applicant submits copies of the documents listed on the attached Form PTO-1449.

The listed documents were recently cited in a corresponding PCT application, and a copy of the International Search Report is being submitted herewith for purposes of convenience.

The Commissioner is authorized to charge Deposit Order Account No. 19-0079 for any further fee that is required.

Respectfully submitted,

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I hereby certify that this paper (along with any paper referred to as being attached or enclosed) is being deposited with the United States Postal Service on the date shown below with sufficient postage as first class mail in an envelope addressed to the Mail Stop DD, Commissioner of Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

(Rev. 5/92)

FORM PTO-1449 SAMUELS, GAUTHIER & STEVENS LLP 225 Franklin Street, Boston, MA 02110

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APPLICANT: McGill et al.

FILING DATE: August 1, 2003

ATTORNEY DOCKET NO.

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INFORMATION DISCLOSURE FEB 2 6 200 B

U.S. PATENT DOCUMENTS

MIT.9944

RADE			0.5. 1.	ATENT DOCUMENT			
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	AA	2001/0028061	10/11/2001	Hosoba et al.			03/29/2001
	AB	6,108,360	08/22/2000	Razeghi			06/06/1997
	AC						
	AD						
	AE						
	AF						
	AG						
	····		FOREIGN	PATENT DOCUME	NTS		
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES NO
	AH						
	<u> </u>	OTHER D	OCUMENTS	(Including Author, Title, Dat	te, Pertinent F	ages, Etc.)	
EXAMINER INITIAL							
	AI	"Evolution of microstructure and dislocation dynamics in In _x Ga _{1-x} P graded Buffers grown on GaP by metalorganic vapor phase epitaxy: engineering device-quality substrate materials," Kim et al. <i>J. Vac. Sci. Technol. B.</i> Jul/Aug 1999. Vol. 17. "Yellow-Green emission for ETS-LEDs and Lasers based on a strained InGaP quantum well heterostructure grown on a transparent, compositionally graded AlInGaP buffer," McGill et al. <i>Mat. Res. Soc. Symp.</i> 2003: Vol. 744.					
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AN

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Initial if citation considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.